

MMBT5088LT1G, MMBT5089LT1G

Low Noise Transistors

NPN Silicon

Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage MMBT5088 MMBT5089	V_{CEO}	30 25	Vdc
Collector – Base Voltage MMBT5088 MMBT5089	V_{CBO}	35 30	Vdc
Emitter – Base Voltage	V_{EBO}	4.5	Vdc
Collector Current – Continuous	I_C	50	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

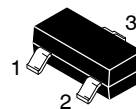
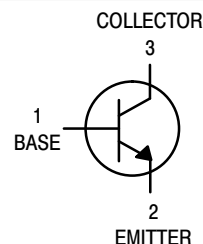
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- FR-5 = 1.0 x 0.75 x 0.062 in.
- Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



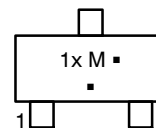
ON Semiconductor®

<http://onsemi.com>



SOT-23 (TO-236)
CASE 318
STYLE 6

MARKING DIAGRAM



1x = Device Code
x = Q for MMBT5088LT1
x = R for MMBT5089LT1
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MMBT5088LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBT5089LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMBT5088LT1G, MMBT5089LT1G

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage ($I_C = 1.0 \text{ mA}$, $I_E = 0$)	$V_{(BR)CEO}$	30 25	– –	Vdc
Collector – Base Breakdown Voltage ($I_C = 100 \mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	35 30	– –	Vdc
Collector Cutoff Current ($V_{CB} = 20 \text{ Vdc}$, $I_E = 0$) ($V_{CB} = 15 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	– –	50 50	nAdc
Emitter Cutoff Current ($V_{EB(off)} = 3.0 \text{ Vdc}$, $I_C = 0$) ($V_{EB(off)} = 4.5 \text{ Vdc}$, $I_C = 0$)	I_{EBO}	– –	50 100	nAdc
ON CHARACTERISTICS				
DC Current Gain ($I_C = 100 \mu\text{A}$, $V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 1.0 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$)	h_{FE}	300 400 350 450 300 400	900 1200 – – – –	–
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_E = 1.0 \text{ mA}$)	$V_{CE(sat)}$	–	0.5	Vdc
Base – Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_E = 1.0 \text{ mA}$)	$V_{BE(sat)}$	–	0.8	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current – Gain — Bandwidth Product ($I_C = 500 \mu\text{A}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 20 \text{ MHz}$)	f_T	50	–	MHz
Collector – Base Capacitance ($V_{CB} = 5.0 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$ emitter guarded)	C_{cb}	–	4.0	pF
Emitter – Base Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_C = 0$, $f = 1.0 \text{ MHz}$ collector guarded)	C_{eb}	–	10	pF
Small Signal Current Gain ($I_C = 1.0 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	h_{fe}	350 450	1400 1800	–
Noise Figure ($I_C = 100 \mu\text{A}$, $V_{CE} = 5.0 \text{ Vdc}$, $R_S = 10 \text{ k}\Omega$, $f = 1.0 \text{ kHz}$)	NF	– –	3.0 2.0	dB

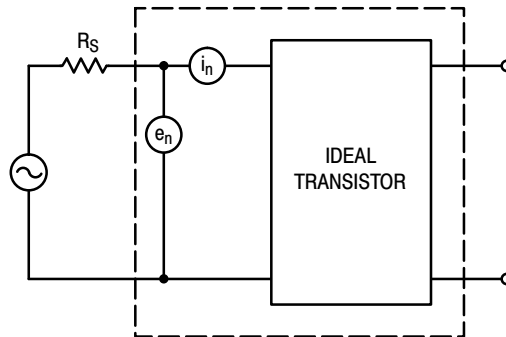


Figure 1. Transistor Noise Model

[查询"MMBT5088LT1-D"供应商](#)

NOISE CHARACTERISTICS

($V_{CE} = 5.0 \text{ Vdc}$, $T_A = 25^\circ\text{C}$)

NOISE VOLTAGE

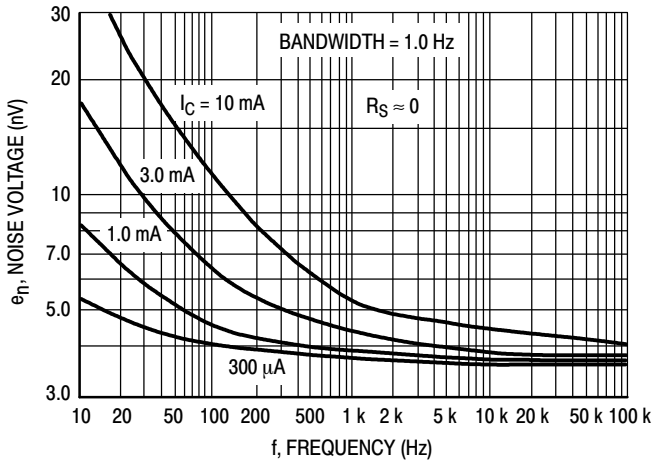


Figure 2. Effects of Frequency

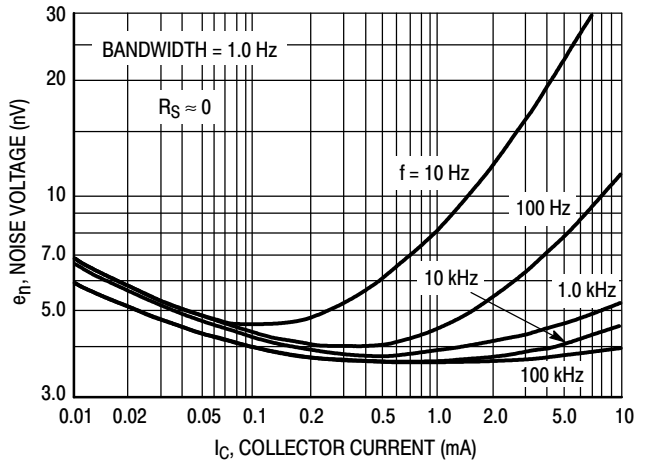


Figure 3. Effects of Collector Current

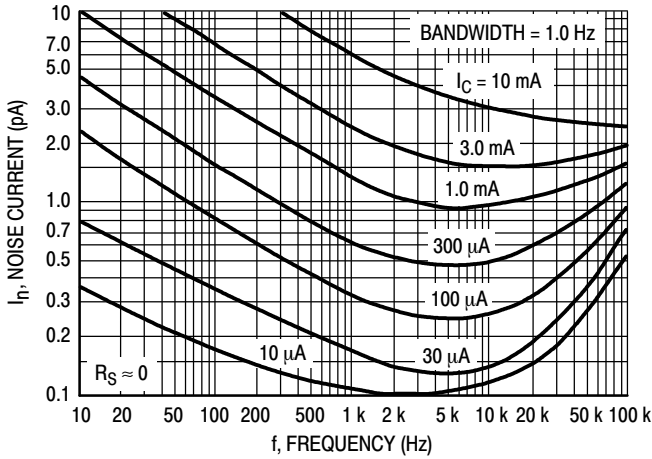


Figure 4. Noise Current

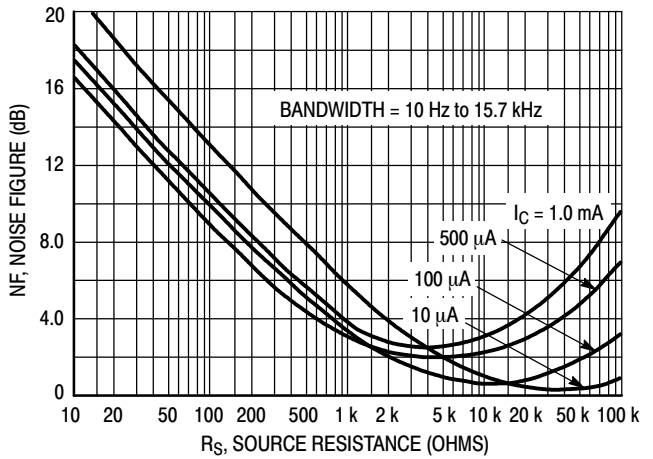


Figure 5. Wideband Noise Figure

100 Hz NOISE DATA

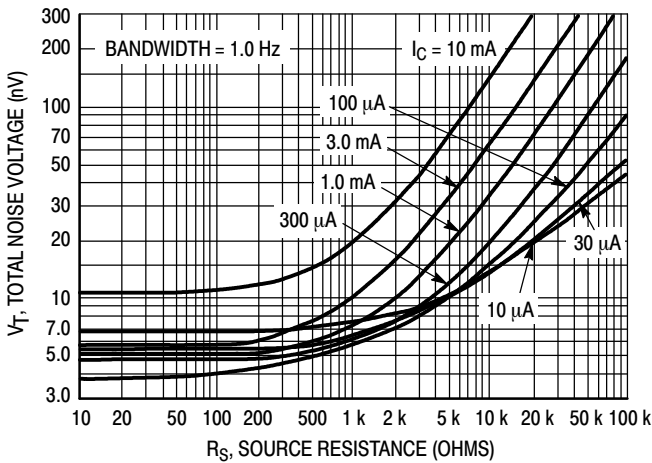


Figure 6. Total Noise Voltage

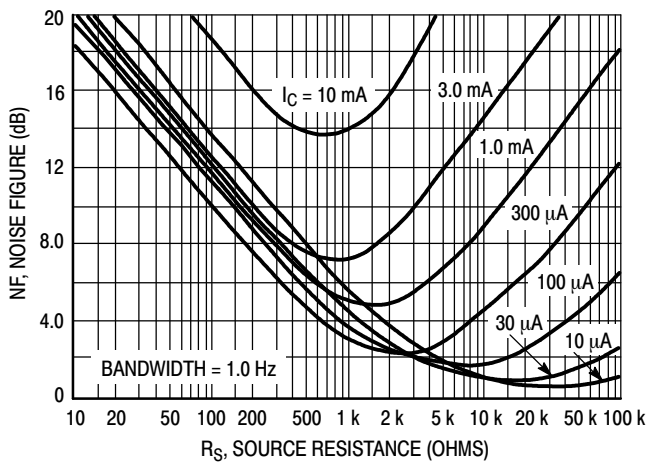
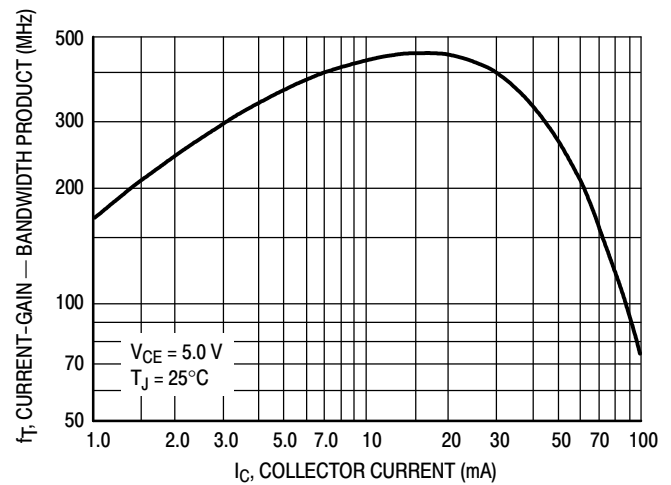
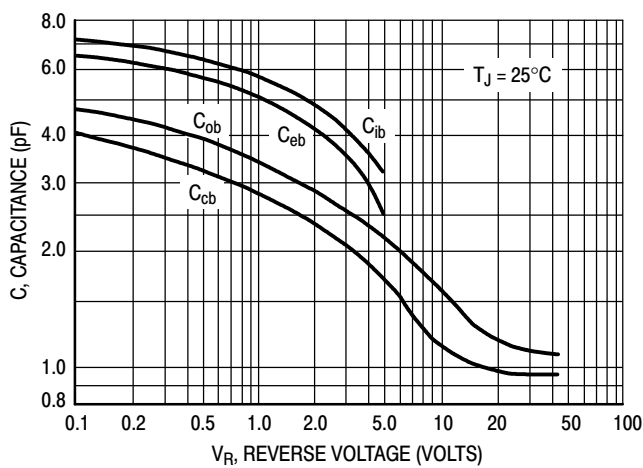
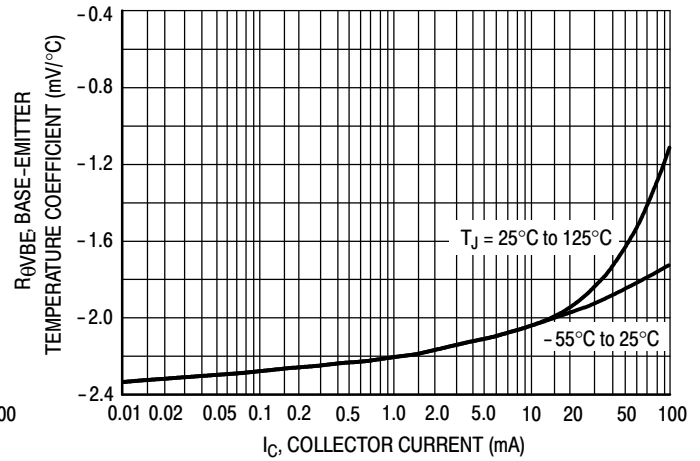
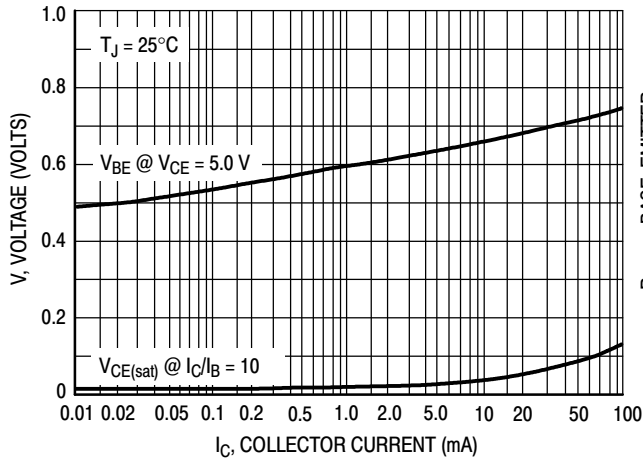
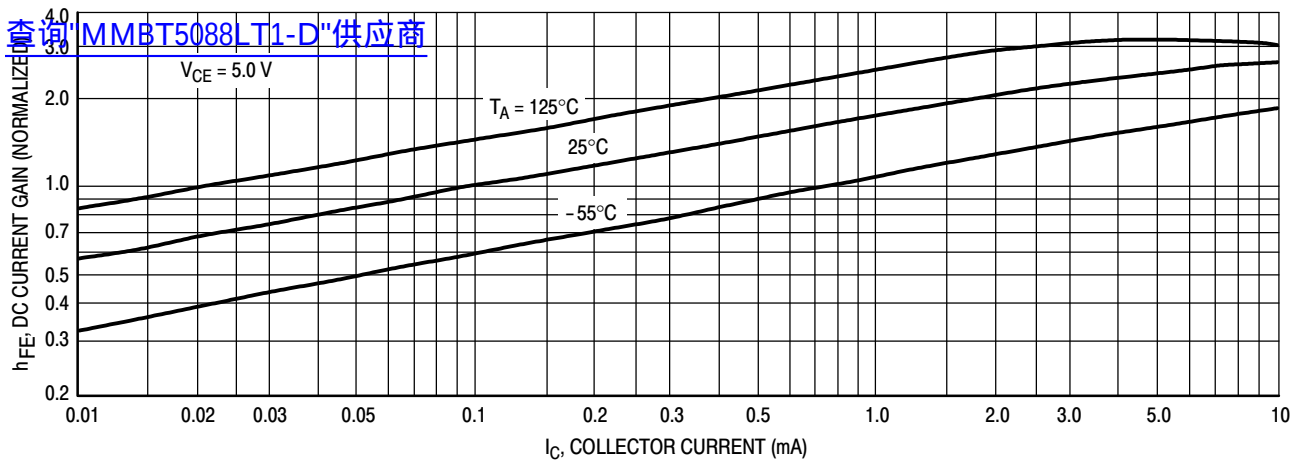


Figure 7. Noise Figure

MMBT5088LT1G, MMBT5089LT1G

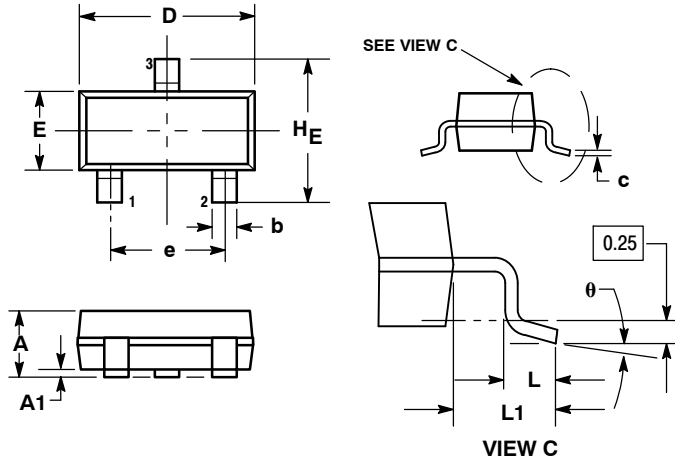


MMBT5088LT1G, MMBT5089LT1G

[查询"MMBT5088LT1-D"供应商](#)

PACKAGE DIMENSIONS

SOT-23 (TO-236)
CASE 318-08
ISSUE AN



NOTES:

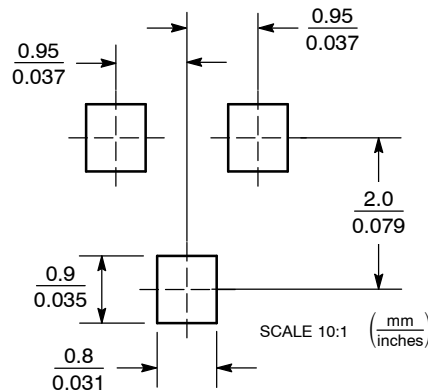
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local
Sales Representative

MMBT5088LT1/D